imall

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2-Bit Bus Switch

The 7WB3125 is an advanced high-speed low-power 2-bit bus switch in ultra-small footprints.

Features

- High Speed: $t_{PD} = 0.25 \text{ ns} (Max) @ V_{CC} = 4.5 \text{ V}$
- 3 Ω Switch Connection Between 2 Ports
- Power Down Protection Provided on Inputs
- Zero Bounce
- TTL-Compatible Control Inputs
- Ultra–Small Pb–Free Packages
- These are Pb–Free Devices



ON Semiconductor®

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		MARKING DIAGRAMS
1	UDFN8 MU SUFFIX CASE 517AJ	AKM ⊖ ■
	Micro8™ DM SUFFIX CASE 846A	8 1125 AYW• O • 1 1 1 1 1
	UDFN8 1.95 x 1.0 CASE 517CA	1 • X M
A Y W M • (Note: Micr	= Assembly Lo = Year = Work Week = Date Code = Pb-Free Pac odot may be in eithe	kage

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

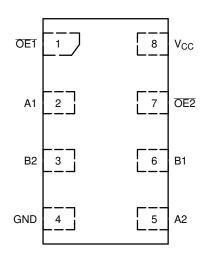
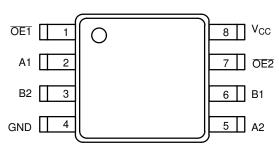


Figure 1. UDFN8 (Top Thru–View)





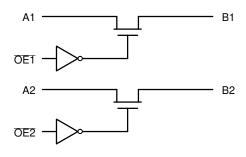


Figure 3. Logic Diagram

FUNCTION TABLE

Input OEn	Function
L	Bn = An
Н	Disconnect

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage	-0.5 to +7.0	V	
V _{IN}	Control Pin Input Voltage	-0.5 to +7.0	V	
V _{I/O}	Switch Input / Output Voltage	-0.5 to +7.0	V	
Ι _{ΙΚ}	Control Pin DC Input Diode Current V _{IN} < GND	-50	mA	
Ι _{ΟΚ}	Switch I/O Port DC Diode Current V _{I/O} < GND	-50	mA	
lo	ON-State Switch Current	± 128	mA	
	Continuous Current Through V _{CC} or GND	± 150	mA	
I _{CC}	DC Supply Current Per Supply Pin	± 150	mA	
I _{GND}	DC Ground Current per Ground Pin	± 150	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C	
TJ	Junction Temperature Under Bias	150	°C	
θ_{JA}	Thermal Resistance UDFN8 (Note 1) Micro8	111 392	°C/W	
PD	Power Dissipation in Still Air at 85°C UDFN8 Micro8	1127 319	mW	
MSL	Moisture Sensitivity	Level 1		
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in		
V _{ESD}	ESD Withstand Voltage Human Body Mode (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V	
ILATCHUP	Latchup Performance Above V _{CC} and Below GND at 125°C (Note 5)	±200	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
 Tested to EIA / JESD22-A114-A.

3. Tested to EIA / JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	4.0	5.5	V	
V _{IN}	Control Pin Input Voltage	0	5.5	V	
V _{I/O}	Switch Input / Output Voltage	0	5.5	V	
T _A	Operating Free–Air Temperature	-55	+125	°C	
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate	Control Input Switch I/O	0 0	5 DC	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

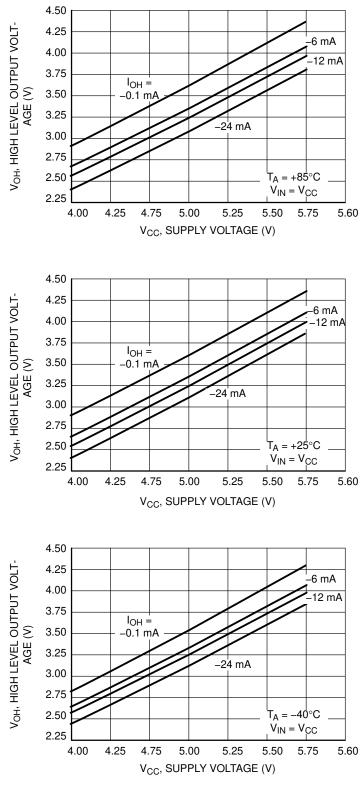
			V _{CC}	T _A = 25°C		T _A = –55°C to +125°C			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Unit
V _{IK}	Clamp Diode Voltage	$I_{I/O} = -18 \text{ mA}$	4.5			-1.2		-1.2	V
V _{IH}	High-Level Input Voltage (Control)		4.0 to 5.5	2.0			2.0		V
V _{IL}	Low-Level Input Voltage (Control)		4.0 to 5.5			0.8		0.8	V
V _{OH}	Output Voltage High	See Figure 4							
I _{IN}	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±0.1		±1.0	μA
I _{OFF}	Power Off Leakage Current	$V_{I/O} = 0$ to 5.5 V	0			±0.1		±1.0	μA
Icc	Quiescent Supply Current	$I_{O} = 0,$ $V_{IN} = V_{CC} \text{ or } 0 \text{ V}$	5.5			±0.1		±1.0	μA
Δl _{CC}	Increase in Supply Current (Control Pin)	One input at 3.4 V; Other inputs at V _{CC} or GND	ther inputs at				2.5	mA	
R _{ON}	Switch ON Resistance	$V_{I/O} = 0,$ $I_{I/O} = 64 \text{ mA}$ $I_{I/O} = 30 \text{ mA}$	4.5		3 3	7 7		7 7	Ω
		$V_{I/O} = 2.4,$ $I_{I/O} = 15 \text{ mA}$			6	15		15	
		V _{I/O} = 2.4, I _{I/O} = 15 mA	4.0		10	20		20	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

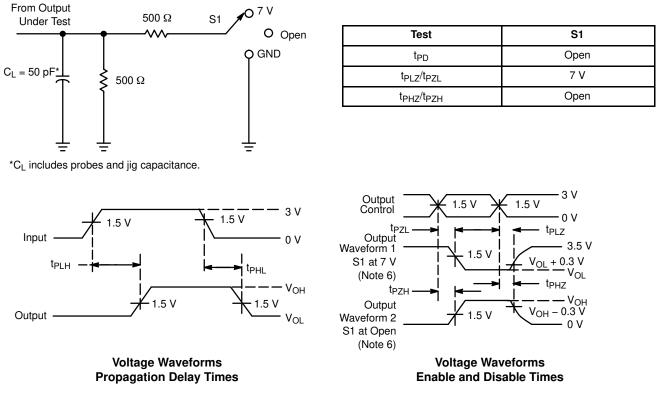
			V _{CC}	T _A = 25 °C		T _A = –55°C to +125°C			
Symbol	Parameter	Test Condition	(V)	Min	Тур	Max	Min	Мах	Unit
t _{PD}	Propagation Delay, Bus to Bus	See Figure 5	4.0 to 5.5			0.25		0.25	ns
t _{EN}	Output Enable Time	See Figure 5	4.5 to 5.5	0.8	2.5	4.2	0.8	4.2	ns
			4.0	0.8	3.0	4.6	0.8	4.6	
t _{DIS}	Output Disable Time		4.5 to 5.5	0.8	3.0	4.8	0.8	4.8	ns
			4.0	0.8	2.9	4.4	0.8	4.4	
C _{IN}	Control Input Capacitance	$V_{IN} = 5 \text{ or } 0 \text{ V}$	5.0		2.5				pF
C _{IO(ON)}	Switch On Capacitance	Switch ON	5.0		10				pF
C _{IO(OFF)}	Switch Off Capacitance	Switch OFF	5.0		5				pF

TYPICAL DC CHARACTERISTICS





AC LOADING AND WAVEFORMS



Parameter Measurement Information

6. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control

- 7. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns. 8. The outputs are measured one at a time, with one transition per measurement.

9. t_{PLZ} and t_{PHZ} are the same as t_{DIS}.

10. t_{PZL} and t_{PZH} are the same as t_{EN} . 11. t_{PHL} and t_{PLH} are the same as t_{PD} .



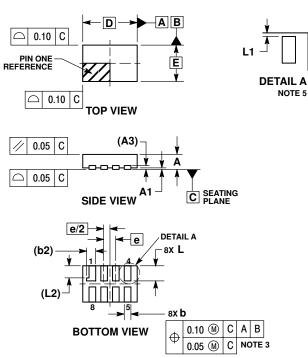
ORDERING INFORMATION

Device	Package	Shipping [†]
7WB3125MUTAG	UDFN8 (Pb–Free)	3000 / Tape & Reel
7WB3125DMR2G	Micro8 (Pb–Free)	4000 / Tape & Reel
7WB3125DMUTCG	UDFN8, 1.95 x 1.0, 0.5 mm Pitch (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

UDFN8 1.8 x 1.2, 0.4P CASE 517AJ ISSUE O

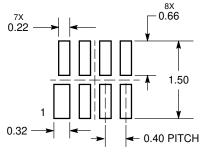


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

- CONTROLLING DIMENSION: MILLIMETERS
 DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL TIP.
 MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH MAY NOT EXCEED 0.03 ONTO BOTTOM SURFACE OF TERMINALS.
 DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

Concincenterie							
	MILLIM	MILLIMETERS					
DIM	MIN	MIN MAX					
Α	0.45	0.55					
A1	0.00	0.00 0.05					
A3	0.127	' REF					
b	0.15 0.25						
b2	0.30 REF						
D	1.80	BSC					
Е	1.20	BSC					
е	0.40	BSC					
L	0.45	0.55					
L1	0.00	0.03					
L2	0.40	REF					

MOUNTING FOOTPRINT* SOLDERMASK DEFINED

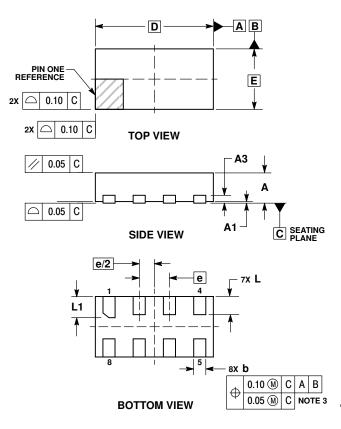


DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

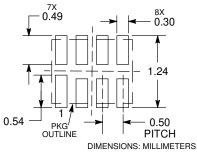
UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O



NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FL						
	MILLIN	MILLIMETERS				
DIM	MIN	MAX				
Α	0.45	0.55				
A1	0.00	0.05				
A3	0.13	REF				
b	0.15	0.25				
D	1.95	BSC				
Е	1.00	BSC				
е	0.50	BSC				
L	0.25	0.35				
L1	0.30 0.40					

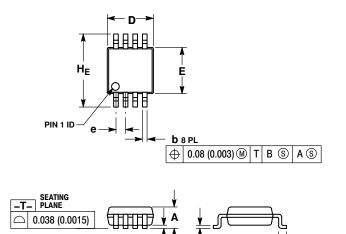
RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

Micro8[™] CASE 846A ISSUE H

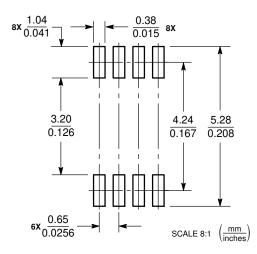


NOTES 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- DIMENSIONING DIMENSIONING PER ANOT TH-JON, 1962. CONTROLLING DIMENSION MILLIMETER. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS, MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 3.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 4.
- 5. 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α			1.10			0.043	
A1	0.05	0.08	0.15	0.002	0.003	0.006	
b	0.25	0.33	0.40	0.010	0.013	0.016	
С	0.13	0.18	0.23	0.005	0.007	0.009	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E	2.90	3.00	3.10	0.114	0.118	0.122	
е		0.65 BSC			0.026 BSC)	
L	0.40	0.55	0.70	0.016	0.021	0.028	
HE	4.75	4.90	5.05	0.187	0.193	0.199	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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